



FCX591AQ

#### **40V PNP SILICON PLANAR MEDIUM POWER TRANSISTOR**

#### **Description**

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

#### **Features**

- BV<sub>CEO</sub> > -40V
- Maximum Continuous Current I<sub>C</sub> = -1A
- Low Saturation Voltage V<sub>CE(SAT)</sub> < -500mV @ -1A</li>
- Complementary NPN type: FCX491AQ
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

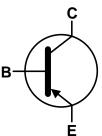
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>@3</a>
- Weight: 0.05 grams (Approximate)

### **Application**

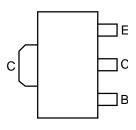
- Power MOSFET & IGBT Gate Driving
- Low Loss Power Switching



Top View



Device Symbol



Top View Pin Out

#### Ordering Information (Note 5)

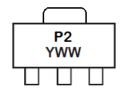
Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FCX591AQTA	P2	7	12	1,000

Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**

SOT89



P2 = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 6 = 2016) WW = Week Code (01 to 53)



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-40	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	Ісм	-2	А
Peak Base Current	I <sub>B</sub>	-200	mA

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	1	W
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction to Leads (Note 7)	$R_{ heta JL}$	10.01	°C/W
Operating and Storage Temperature Range	$T_{J}, T_{STG}$	-65 to +150	°C

# ESD Ratings (Note 8)

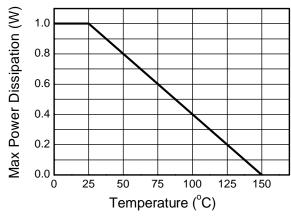
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

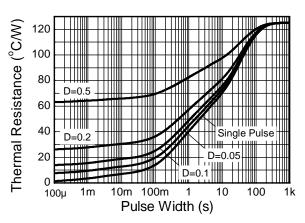
Notes:

- 6. For a device surface mounted on 15mm X 15mm FR-4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
- 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



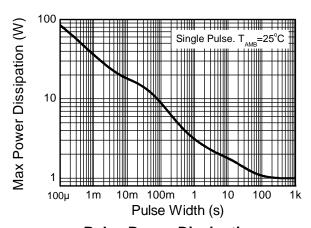
# **Thermal Characteristics and Derating Information**





# **Derating Curve**

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



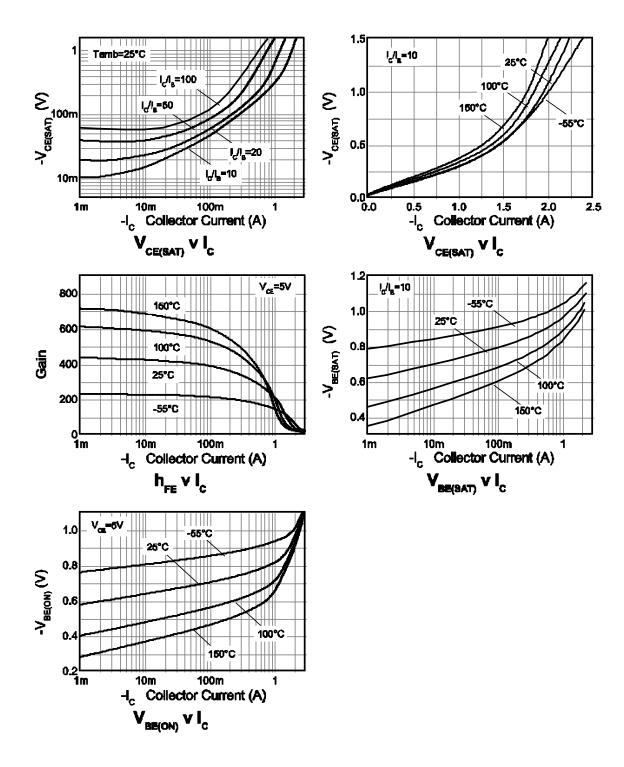
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-40	-	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-40	-	-	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-	-	V	$I_E = -100 \mu A$
Collector Base Cutoff Current	I <sub>CBO</sub>	-	-	-100	nA	V <sub>CB</sub> = -30V
Emitter Base Cutoff Current	I <sub>EBO</sub>	-	-	-100	nA	V <sub>EB</sub> = -4V
Collector Cutoff Current	I <sub>CES</sub>	-	-	-100	nA	V <sub>CES</sub> = -30V
DC Current Transfer Static Ratio (Note 9)	h <sub>FE</sub>	300 300 250 160 30	- - - -	- 800 - - -	-	$I_{C} = -1mA$ , $V_{CE} = -5V$ $I_{C} = -100mA$ , $V_{CE} = -5V$ $I_{C} = -500mA$ , $V_{CE} = -5V$ $I_{C} = -1A$ , $V_{CE} = -5V$ $I_{C} = -2A$ , $V_{CE} = -5V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(SAT)</sub>	- - -	- - -	-0.2 -0.35 -0.5	V	$I_C = -100$ mA, $I_B = -1$ mA $I_C = -500$ mA, $I_B = -20$ mA $I_C = -1$ A, $I_B = -100$ mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(SAT)</sub>	-	-	-1.1	V	$I_C = -1A$ , $I_B = -50mA$
Base-Emitter Turn-on Voltage (Note 9)	V <sub>BE(ON)</sub>	-	-	-1.0	V	$I_C = -1A$ , $V_{CE} = -5V$
Transitional Frequency	f⊤	150	-	-	MHz	$I_E = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 100MHz
Output Capacitance	$C_{obo}$	-	-	10	pF	$V_{CB} = -10V$ , $f = 1MHz$

Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



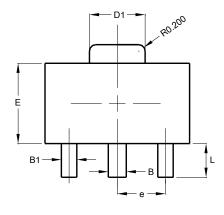
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

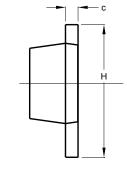


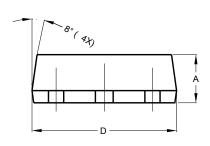


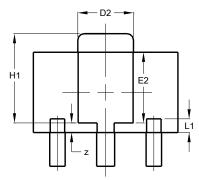
# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.





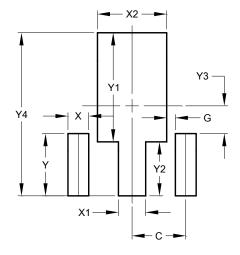




SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.500
G	0.244
Х	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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